

Form PTO 1449
(Modified)U.S. DEPARTMENT OF COMMERCE
PATENT AND TRADEMARK OFFICE

ATTY DOCKET NO.

218447US2TTC

SERIAL NO.

NEW APPLICATION

LIST OF REFERENCES CITED BY APPLICANT

APPLICANT

Akira GODA, et al.

FILING DATE

HEREWITH

GROUP

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
	AA						
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						
	AL						
	AM						
	AN						

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION	
					YES	NO
<i>m</i>	AO	2000-286349	10/13/00	JAPAN		X
	AP	8-17948	01/19/96	JAPAN		X
	AQ	10-256399	09/25/98	JAPAN		X
	AR	4-12573	01/17/92	JAPAN		X
	AS					
	AT					
	AU					
	AV					

OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)

<i>m</i>	AW	S. ARITOME, et al., "A. 0.67 μ m" Self-Aligned Shallow Trench Isolation Cell(SA-STI Cell) For 3v-only 256Mbit NAND EEPROMs", IEDM TECH. DIGEST, 1994, pgs. 3.6.1-3.6.4
	AX	
	AY	
	AZ	

☐ Additional References sheet(s) attached

Examiner

Date Considered

NOV 5 2001

*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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01/30/02